

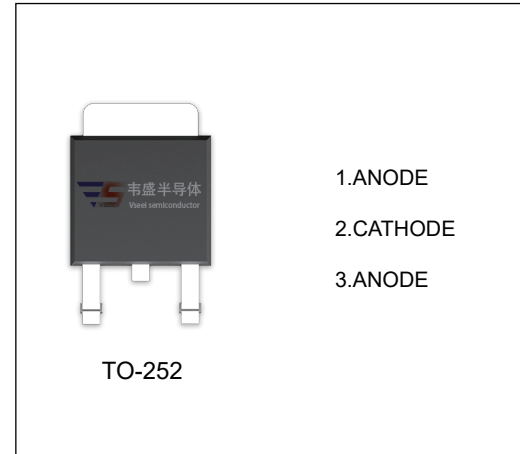
SBDD10200CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	10 (2×5) A
V_{RRM}	200 V
T_j	150 °C
$V_{F(typ)}$	0.72V (@Tj=125°C)

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	200	V
V_{RWM}	Working peak reverse voltage		
V_R	DC blocking voltage		
$V_{R(RMS)}$	RMS reverse voltage	140	V
I_O	Average rectified output current	10	A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	120	A
$R_{\theta JC}$	Thermal resistance from junction to case	5.0	°C/W
$R_{\theta JA}$	Thermal resistance from junction to ambient	100	°C/W
T_j	Junction temperature	150	°C
T_{stg}	Storage temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1\text{mA}$	200			V
Reverse current	I_R	$V_R=200\text{V}$	$T_j=25^{\circ}\text{C}$	1.0	100	uA
			$T_j=125^{\circ}\text{C}$	1.0		mA
Forward voltage	V_F	$I_F=3\text{A}$	$T_j=25^{\circ}\text{C}$	0.80		V
			$T_j=125^{\circ}\text{C}$	0.67		V
		$I_F=5\text{A}$	$T_j=25^{\circ}\text{C}$	0.84	0.92	V
			$T_j=125^{\circ}\text{C}$	0.72		V

*Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycles $\leq 2.0\%$.

FIG.1: FORWARD CURRENT DERATING CURVE

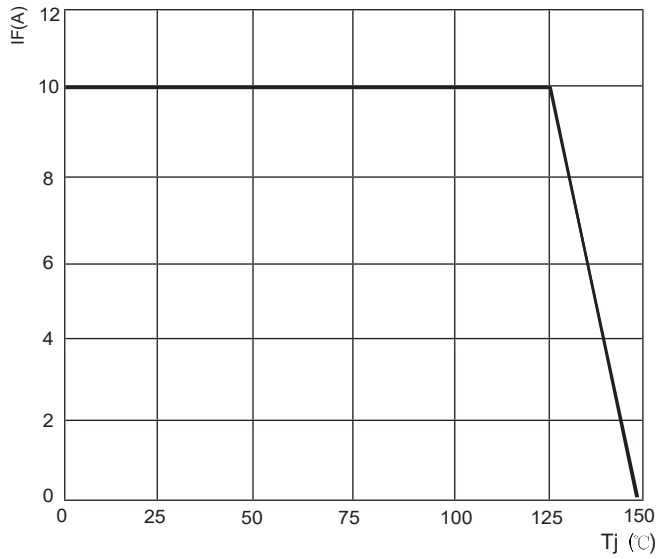


FIG.2: TYPICAL FORWARD CHARACTERISTICS

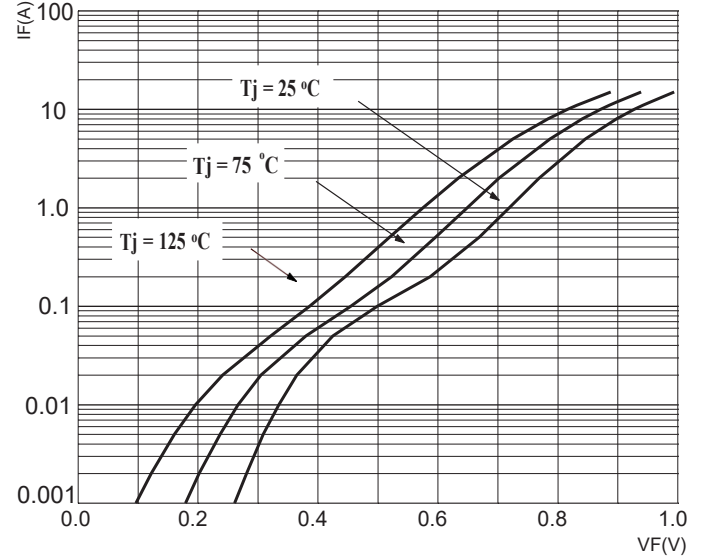


FIG.3: TOTAL CAPACITANCE DERATING CURVE

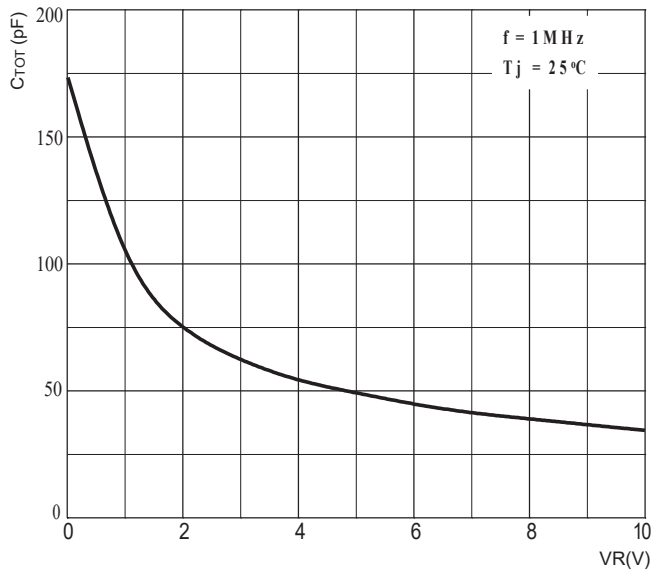


FIG.4: TYPICAL REVERSE CHARACTERISTICS

